## NSN 5962-01-358-0909

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-358-0909

**Maximum Power Dissipation Rating:** 300.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Current Rating Per Characteristic:** 85.00 milliamperes supply **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds delay Memory Device Type: Prom Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** Yes - demil/mli Fiig: A458a0